

Docket: CS 99 - 065  
S/N: 09/442,499

GAU/1763  
L\$



To: Commissioner of Patents and Trademarks  
Washington, D.C. 20231

From: George O. Saile, Reg. No. 19,572  
20 McIntosh Drive  
Poughkeepsie, N.Y. 12603

Subject:

Serial No. 09/442,499	Filed: 11/18/99
Inventor: Ho	
Title: Plasma Etch Method For Forming Plasma Etched Silicon Layer	
Group Art Unit: 1763	Examiner: Goudreau, B.
Attorney Docket: CS 99 - 065	

#4A  
3/1/01

### RESPONSE TO PATENT OFFICE ACTION

Dear Sir:

In response to the office action dated 12/11/00, please consider the following remarks:

### CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner of Patent and Trademarks, Washington, D.C. 20231, on FEB. 28, 2001.

Signature/Date [Signature] 2/28/01

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